Low-power 2-input NAND Schmitt trigger

Rev. 6 — 1 May 2019

1. General description

The 74AUP1G132 provides the single 2-input NAND Schmitt trigger function which accept standard input signals. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_{H-} .

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator.

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4. Ordering information

Table 1. Ordering information

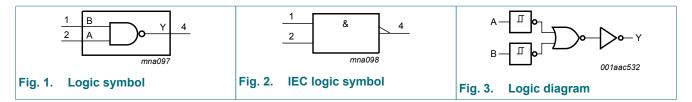
Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G132GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74AUP1G132GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G132GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891
74AUP1G132GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G132GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202
74AUP1G132GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm	SOT1226

5. Marking

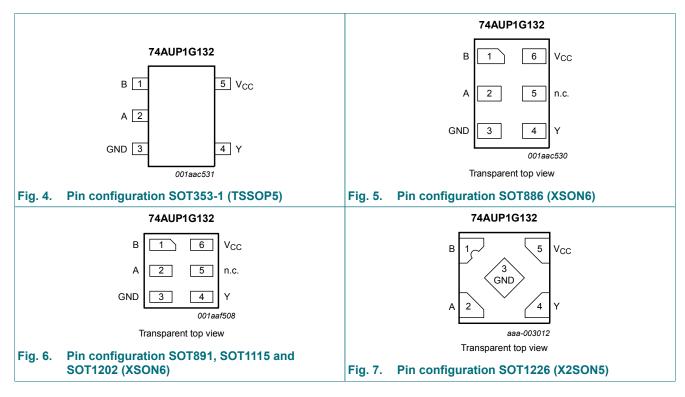
Table 2. Marking	
Type number	Marking code [1]
74AUP1G132GW	aE
74AUP1G132GM	aE
74AUP1G132GF	aE
74AUP1G132GN	aE
74AUP1G132GS	aE
74AUP1G132GX	aE

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information



7.1. Pinning

7.2. Pin description

Symbol	Pin	Pin			
	TSSOP5 and X2SON5	XSON6			
В	1	1	data input		
A	2	2	data input		
GND	3	3	ground (0 V)		
Y	4	4	data output		
n.c.	-	5	not connected		
V _{CC}	5	6	supply voltage		

Table 2 Din description

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output	
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

Table 6. Recommended operating conditions

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C	· · · · · ·				_
V _{OH}	HIGH-level output	$V_{I} = V_{T+}$ or V_{T-}				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output	$V_1 = V_{T+}$ or V_{T-}				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
Δl _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μA
CI	input capacitance	V_{I} = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	V_{O} = GND; V_{CC} = 0 V	-	1.7	-	pF
T _{amb} = -4	40 °C to +85 °C				1	_
V _{OH}	HIGH-level output	$V_{I} = V_{T+}$ or V_{T-}				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	_	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output	$V_{I} = V_{T+} \text{ or } V_{T-}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_0 = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μA
T _{amb} = -	40 °C to +125 °C					
V _{OH}	HIGH-level output	$V_{I} = V_{T+} \text{ or } V_{T-}$				
	voltage	$I_{\rm O}$ = -20 µA; $V_{\rm CC}$ = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I_0 = -2.3 mA; V_{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{T+} \text{ or } V_{T-}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
∆I _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V} $ [1]	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

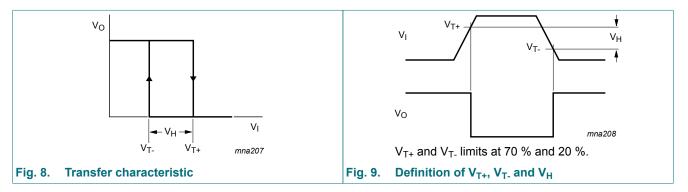
11.1. Transfer characteristics

Table 8. Transfer characteristics

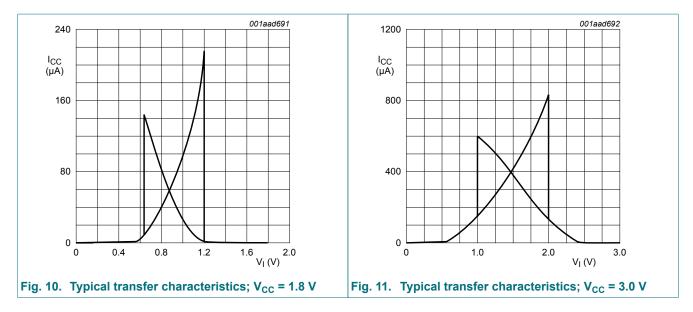
Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 13.

Symbol	Parameter	Conditions		25 °C		-	°C to 5 °C	-	°C to 5 °C	Unit
			Min	Тур	Мах	Min	Мах	Min	Max	1
V _{T+}	positive-going threshold voltage	see Fig. 8 and Fig. 9								
		V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V _{T-}	negative-going threshold voltage	see Fig. 8 and Fig. 9								
		V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 8</u> , <u>Fig. 9</u> , <u>Fig. 10</u> and <u>Fig. 11</u>								
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

11.2. Waveforms transfer characteristics



Low-power 2-input NAND Schmitt trigger



12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 13.

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Typ [1]	Max	Min	Мах	Min	Max	
C _L = 5 p	F									
t _{pd}	propagation	A or B to Y; see <u>Fig. 12</u> [2]								
	delay	V _{CC} = 0.8 V	-	22.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	2.4	16.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	1.9	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	1.7	8.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	1.5	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	1.4	6.2	ns
C _L = 10	pF									
t _{pd}	propagation	A or B to Y; see <u>Fig. 12</u> [2]								
	delay	V _{CC} = 0.8 V	-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	2.7	19.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	2.2	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	2.0	9.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	1.8	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	1.8	7.2	ns
C _L = 15	pF								1	
t _{pd}	propagation	A or B to Y; see <u>Fig. 12</u> [2]								
	delay	V _{CC} = 0.8 V	-	29.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	3.0	21.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	2.5	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	2.3	11.0	ns
		V_{CC} = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	2.1	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.0	ns

74AUP1G132

Low-power 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Typ [1]	Max	Min	Мах	Min	Max	
C _L = 30	pF					-				
t _{pd}	propagation	A or B to Y; see <u>Fig. 12</u> [2]								
	delay	V _{CC} = 0.8 V	-	39.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	3.8	27.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	3.2	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	2.9	14.1	ns
		V_{CC} = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	2.7	11.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	2.7	10.1	ns
C _L = 5 p	F, 10 pF, 15 pl	F and 30 pF							1	
C _{PD}	power dissipation	$ f_i = 1 \text{ MHz}; $ [3] $ V_I = \text{GND to } V_{CC} $								
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC}.
 [2] t_{pd} is the same as t_{PLH} and t_{PHL}.
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW). P_D = C_{PD} × V_{CC}² × f_i × N + Σ(C_L × V_{CC}² × f_o) where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

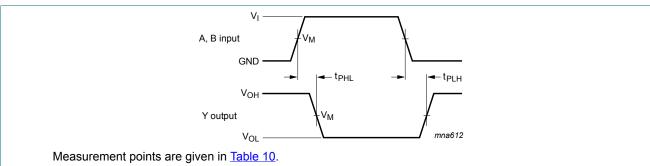
 C_{L} = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveforms and test circuit



 V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig. 12. The data input (A or B) to output (Y) propagation delays

Table 10. Measurement points

Supply voltage	Output	Input				
V _{cc}	V _M	V_{M} V_{i} $t_{r} = t_{f}$				
0.8 V to 3.6 V	$0.5 \times V_{CC}$	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns		

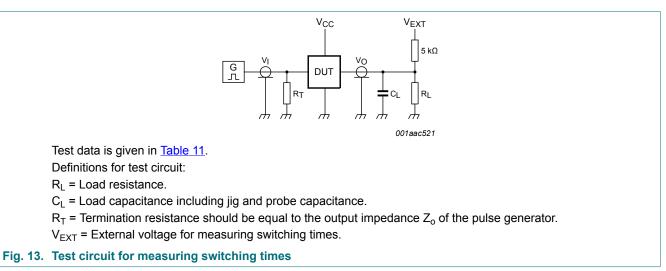


Table 11. Test data

Supply voltage	Load		V _{EXT}			
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}	

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

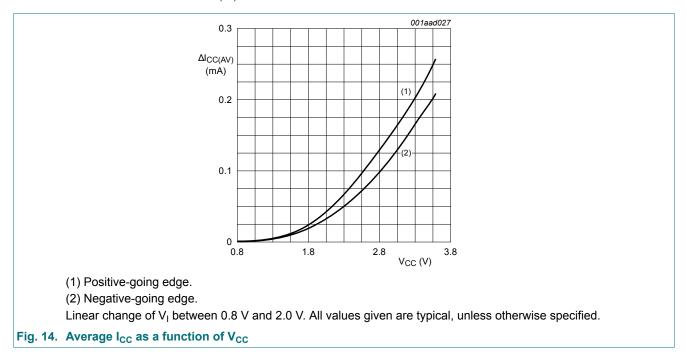
13. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $\mathsf{P}_{\mathsf{add}} = \mathsf{f}_{\mathsf{i}} \times (\mathsf{t}_{\mathsf{r}} \times \Delta \mathsf{I}_{\mathsf{CC}(\mathsf{AV})} + \mathsf{t}_{\mathsf{f}} \times \Delta \mathsf{I}_{\mathsf{CC}(\mathsf{AV})}) \times \mathsf{V}_{\mathsf{CC}} \text{ where:}$

- P_{add} = additional power dissipation (µW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- ΔI_{CC(AV)} = average additional supply current (µA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 14.



74AUP1G132

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14. Package outline

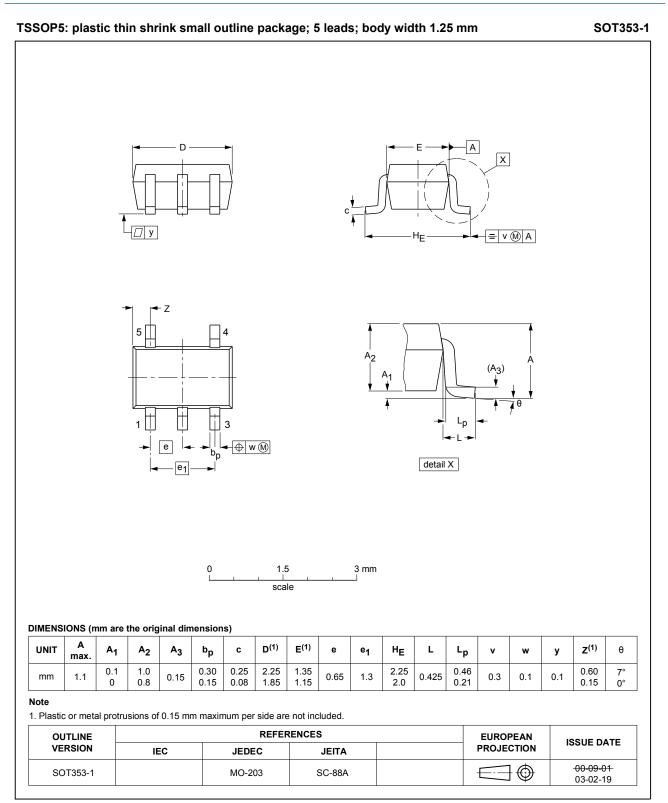


Fig. 15. Package outline SOT353-1 (TSSOP5)

Low-power 2-input NAND Schmitt trigger

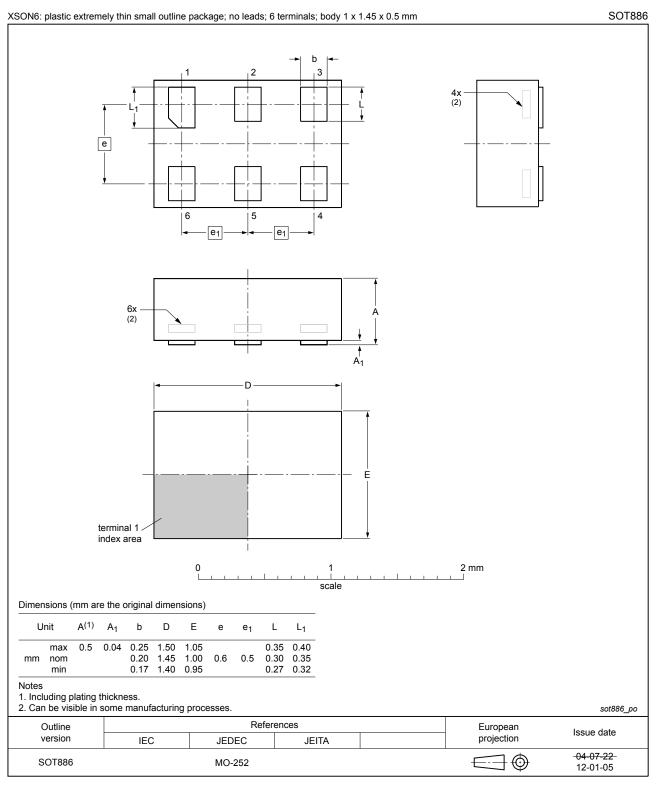


Fig. 16. Package outline SOT886 (XSON6)

Low-power 2-input NAND Schmitt trigger

KSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm							SOT					
			e v	- L ₁ 							4× (1)	-
			6: (1	× I)								
			terr ind	minal 1 - ex area								
0 1 2 mm L												
UNIT	A max	A ₁ max	b	D	Е	е	e ₁	L	L ₁			
mm	0.5	0.04	0.20 0.12	1.05 0.95	1.05 0.95	0.55	0.35	0.35 0.27	0.40 0.32			
lote . Can t	oe visibl	e in son	ne manı	ufacturin	ig proce	sses.		-				
OUTLINE REFERE					ENCES			EUROPEAN	ISSUE DATE			
VERSION			IE	IEC JEDEC			С	JEITA				-05-04-06
	OT891											

Fig. 17. Package outline SOT891 (XSON6)

Low-power 2-input NAND Schmitt trigger

XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

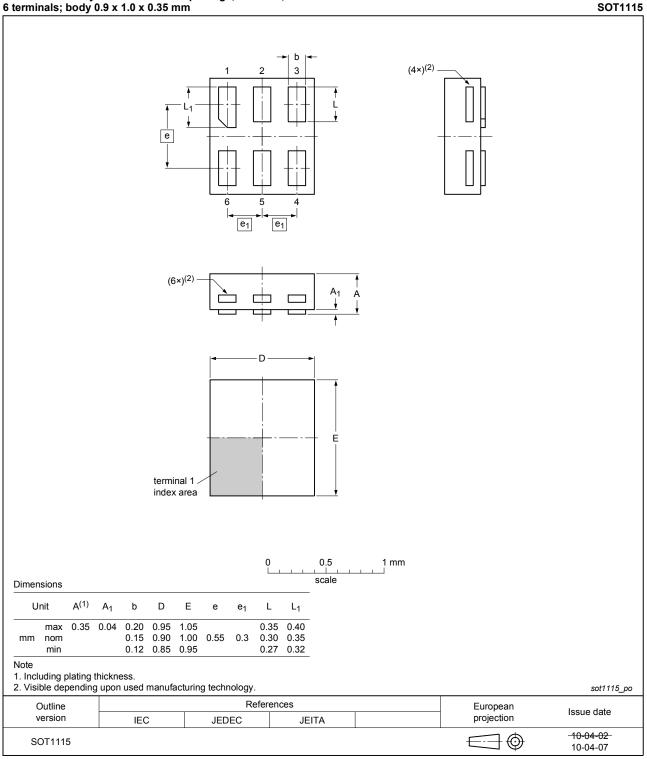
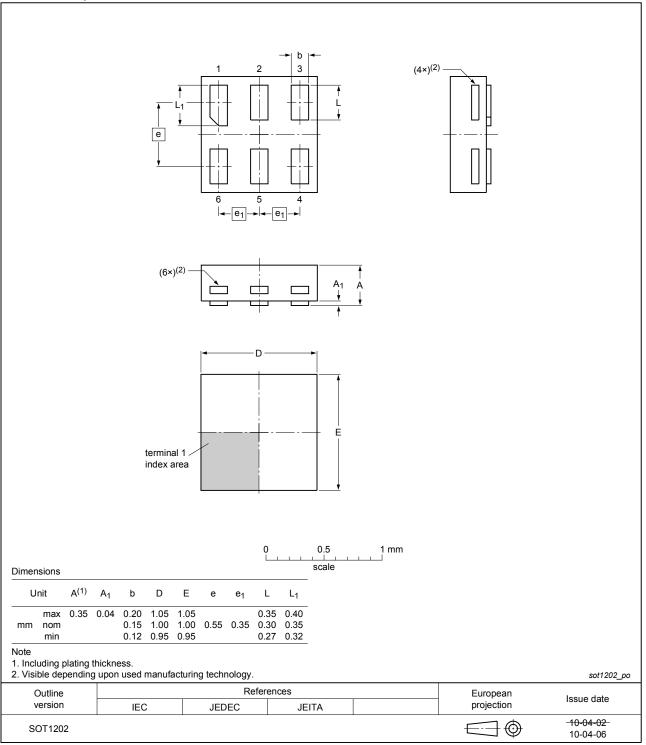


Fig. 18. Package outline SOT1115 (XSON6)

SOT1202

Low-power 2-input NAND Schmitt trigger

XSON6: extremely thin small outline package; no leads;	
6 terminals; body 1.0 x 1.0 x 0.35 mm	





Low-power 2-input NAND Schmitt trigger

X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm SOT1226 A B D X F A A₃ detail X terminal 1 index area е C b-// Y1 C ___ У terminal 1 index area L 5 4 1 mm 0 scale Dimensions D_h Unit A(1) A₁ D Е A₃ b k L е v w у У1 0.35 0.04 0.128 0.85 0.30 0.27 0.85 0.27 max 0.25 0.80 mm nom 0.80 0.22 0.48 0.22 $0.1 \quad 0.05 \quad 0.05 \quad 0.05$ 0.040 0.75 0.20 0.17 min 0.20 0.75 0.17 Note 1. Dimension A is including plating thickness. 2. Plastic or metal protrusions of 0.075 mm maximum per side are not included. sot1226_po References Outline European Issue date version projection IEC JEDEC EIAJ 12-04-10 12-04-25 SOT1226 70 -----

Fig. 20. Package outline SOT1226 (X2SON5)

15. Abbreviations

Table 12. Abbreviations	
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

16. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AUP1G132 v.6	20190501	Product data sheet	-	74AUP1G132 v.5				
Modifications:	of Nexperia Legal texts 	 The format of this data sheet has been read of Nexperia. Legal texts have been adapted to the new <u>Fig. 7</u>: Pin configuration drawing SOT1220 						
74AUP1G132 v.5	20120629	Product data sheet	-	74AUP1G132 v.4				
Modifications:		 Added type number 74AUP1G132GX (SOT1226) Package outline drawing of SOT886 (Fig. 16) modified. 						
74AUP1G132 v.4	20111124	Product data sheet	-	74AUP1G132 v.3				
Modifications:	Legal pages	Legal pages updated.						
74AUP1G132 v.3	20101029	Product data sheet	-	74AUP1G132 v.2				
74AUP1G132 v.2	20090615	Product data sheet	-	74AUP1G132 v.1				
74AUP1G132 v.1	20061020	Product data sheet	-	-				

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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Low-power 2-input NAND Schmitt trigger

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